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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	120MHz
Connectivity	CANbus, I <sup>2</sup> C, IrDA, LINbus, MMC, SPI, UART/USART, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, I <sup>2</sup> S, LCD, POR, PWM, WDT
Number of I/O	82
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	100K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.6V
Data Converters	A/D 16x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f205vct7tr">https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f205vct7tr</a>

### 3.4 Embedded Flash memory

The STM32F20x devices embed a 128-bit wide Flash memory of 128 Kbytes, 256 Kbytes, 512 Kbytes, 768 Kbytes or 1 Mbyte available for storing programs and data.

The devices also feature 512 bytes of OTP memory that can be used to store critical user data such as Ethernet MAC addresses or cryptographic keys.

### 3.5 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a software signature during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

### 3.6 Embedded SRAM

All STM32F20x products embed:

- Up to 128 Kbytes of system SRAM accessed (read/write) at CPU clock speed with 0 wait states
- 4 Kbytes of backup SRAM.

The content of this area is protected against possible unwanted write accesses, and is retained in Standby or VBAT mode.

### 3.7 Multi-AHB bus matrix

The 32-bit multi-AHB bus matrix interconnects all the masters (CPU, DMAs, Ethernet, USB HS) and the slaves (Flash memory, RAM, FSMC, AHB and APB peripherals) and ensures a seamless and efficient operation even when several high-speed peripherals work simultaneously.

The DMA can be used with the main peripherals:

- SPI and I<sup>2</sup>S
- I<sup>2</sup>C
- USART and UART
- General-purpose, basic and advanced-control timers TIMx
- DAC
- SDIO
- Camera interface (DCMI)
- ADC.

### 3.9 Flexible static memory controller (FSMC)

The FSMC is embedded in all STM32F20x devices. It has four Chip Select outputs supporting the following modes: PC Card/Compact Flash, SRAM, PSRAM, NOR Flash and NAND Flash.

Functionality overview:

- Write FIFO
- Code execution from external memory except for NAND Flash and PC Card
- Maximum frequency ( $f_{HCLK}$ ) for external access is 60 MHz

#### LCD parallel interface

The FSMC can be configured to interface seamlessly with most graphic LCD controllers. It supports the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to specific LCD interfaces. This LCD parallel interface capability makes it easy to build cost-effective graphic applications using LCD modules with embedded controllers or high performance solutions using external controllers with dedicated acceleration.

### 3.10 Nested vectored interrupt controller (NVIC)

The STM32F20x devices embed a nested vectored interrupt controller able to manage 16 priority levels, and handle up to 81 maskable interrupt channels plus the 16 interrupt lines of the Cortex<sup>®</sup>-M3.

The NVIC main features are the following:

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Closely coupled NVIC core interface
- Allows early processing of interrupts
- Processing of late arriving, higher-priority interrupts
- Support tail chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimum interrupt latency.

There are three power modes configured by software when the regulator is ON:

- MR is used in the nominal regulation mode
- LPR is used in Stop modes  
The LP regulator mode is configured by software when entering Stop mode.
- Power-down is used in Standby mode.  
The Power-down mode is activated only when entering Standby mode. The regulator output is in high impedance and the kernel circuitry is powered down, inducing zero consumption. The contents of the registers and SRAM are lost).

Two external ceramic capacitors should be connected on  $V_{CAP\_1}$  and  $V_{CAP\_2}$  pin. Refer to [Figure 19: Power supply scheme](#) and [Table 16: VCAP1/VCAP2 operating conditions](#).

All packages have the regulator ON feature.

### 3.16.2 Regulator OFF

This feature is available only on packages featuring the REGOFF pin. The regulator is disabled by holding REGOFF high. The regulator OFF mode allows to supply externally a V12 voltage source through  $V_{CAP\_1}$  and  $V_{CAP\_2}$  pins.

The two 2.2  $\mu$ F ceramic capacitors should be replaced by two 100 nF decoupling capacitors. Refer to [Figure 19: Power supply scheme](#).

When the regulator is OFF, there is no more internal monitoring on V12. An external power supply supervisor should be used to monitor the V12 of the logic power domain. PA0 pin should be used for this purpose, and act as power-on reset on V12 power domain.

In regulator OFF mode, the following features are no more supported:

- PA0 cannot be used as a GPIO pin since it allows to reset the part of the 1.2 V logic power domain which is not reset by the NRST pin.
- As long as PA0 is kept low, the debug mode cannot be used at power-on reset. As a consequence, PA0 and NRST pins must be managed separately if the debug connection at reset or pre-reset is required.

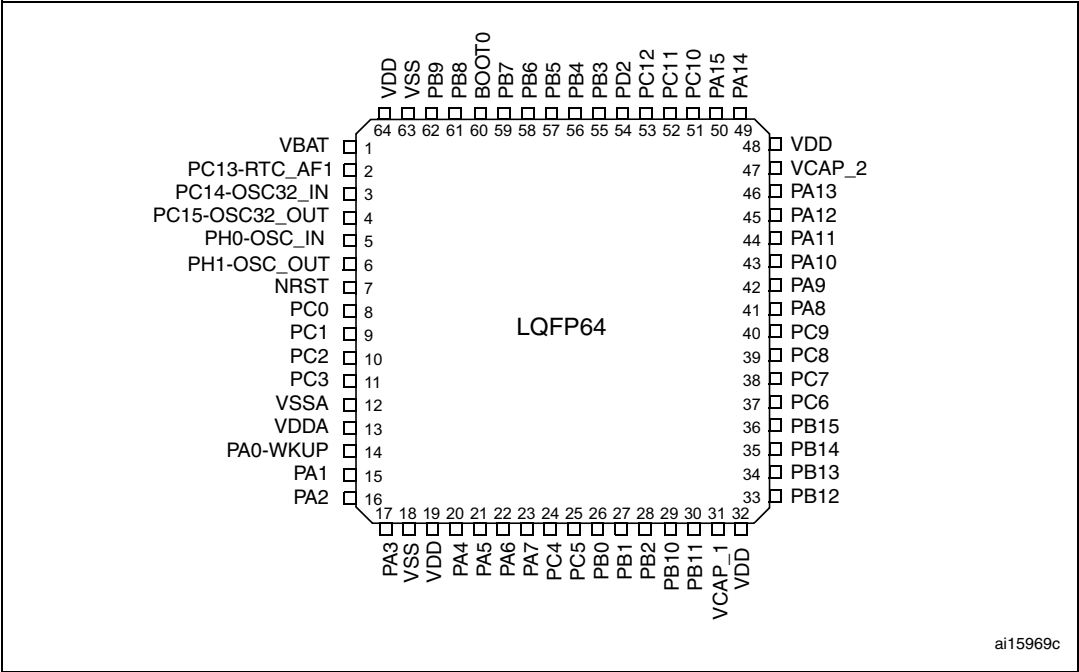
#### Regulator OFF/internal reset ON

On WLCSP64+2 package, this mode is activated by connecting REGOFF pin to  $V_{DD}$  and IRROFF pin to  $V_{SS}$ . On UFBGA176 package, only REGOFF must be connected to  $V_{DD}$  (IRROFF not available). In this mode,  $V_{DD}/V_{DDA}$  minimum value is 1.8 V.

The regulator OFF/internal reset ON mode allows to supply externally a 1.2 V voltage source through  $V_{CAP\_1}$  and  $V_{CAP\_2}$  pins, in addition to  $V_{DD}$ .

4 Pinouts and pin description

Figure 10. STM32F20x LQFP64 pinout



1. The above figure shows the package top view.

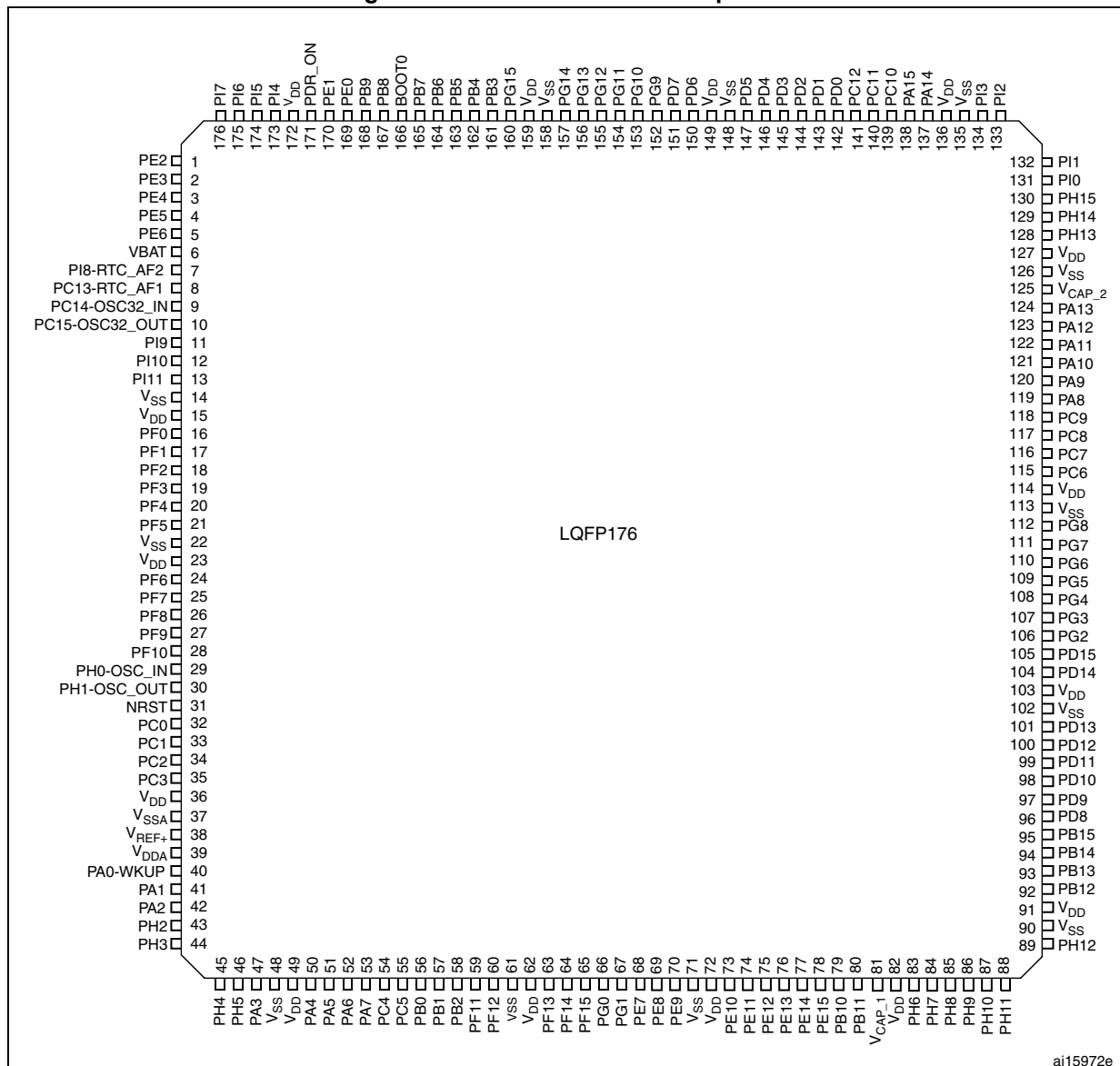
Figure 11. STM32F20x WLCSP64+2 ballout

	1	2	3	4	5	6	7	8	9
A	PA14	PA15	PC12	PB3	PB5	PB7	PB9	VDD	V <sub>BAT</sub>
B	VSS	PA13	PC10	PB4	PB6	BOOT0	PB8	PC13	PC14
C	PA12	VCAP_2	PC11				PD2	IRROFF	PC15
D	PC9	PA11	PA10				PC2	VSS	VDD
E	VDD	PA8	PA9				PA0	NRST	PH0-OSC_IN
F	VSS	PC7	PC8				VREF+	PC1	PH1-OSC_OUT
G	PB15	PC6	PC5				PA3	PC3	PC0
H	PB14	PB13	PB10	PC4	PA6	PA5	REGOFF	PA1	VSS_5
J	PB12	PB11	VCAP_1	PB2	PB1	PB0	PA7	PA4	PA2

ai18470c

1. The above figure shows the package top view.

Figure 14. STM32F20x LQFP176 pinout



ai15972e

1. RFU means "reserved for future use". This pin can be tied to  $V_{DD}$ ,  $V_{SS}$  or left unconnected.
2. The above figure shows the package top view.

Table 8. STM32F20x pin and ball definitions (continued)

Pins						Pin name (function after reset) <sup>(1)</sup>	Pin type	I/O structure	Note	Alternate functions	Additional functions
LQFP64	WLCSP64+2	LQFP100	LQFP144	LQFP176	UFBGA176						
22	H5	31	42	52	P3	PA6	I/O	FT	(4)	SPI1_MISO, TIM8_BKIN, TIM13_CH1, DCMI_PIXCLK, TIM3_CH1, TIM1_BKIN, EVENTOUT	ADC12_IN6
23	J7	32	43	53	R3	PA7	I/O	FT	(4)	SPI1_MOSI, TIM8_CH1N, TIM14_CH1, TIM3_CH2, ETH_MII_RX_DV, TIM1_CH1N, ETH_RMII_CRS_DV, EVENTOUT	ADC12_IN7
24	H4	33	44	54	N5	PC4	I/O	FT	(4)	ETH_RMII_RXD0, ETH_MII_RXD0, EVENTOUT	ADC12_IN14
25	G3	34	45	55	P5	PC5	I/O	FT	(4)	ETH_RMII_RXD1, ETH_MII_RXD1, EVENTOUT	ADC12_IN15
26	J6	35	46	56	R5	PB0	I/O	FT	(4)	TIM3_CH3, TIM8_CH2N, OTG_HS_ULPI_D1, ETH_MII_RXD2, TIM1_CH2N, EVENTOUT	ADC12_IN8
27	J5	36	47	57	R4	PB1	I/O	FT	(4)	TIM3_CH4, TIM8_CH3N, OTG_HS_ULPI_D2, ETH_MII_RXD3, TIM1_CH3N, EVENTOUT	ADC12_IN9
28	J4	37	48	58	M6	PB2/BOOT1 (PB2)	I/O	FT	-	EVENTOUT	-
-	-	-	49	59	R6	PF11	I/O	FT	-	DCMI_D12, EVENTOUT	-
-	-	-	50	60	P6	PF12	I/O	FT	-	FSMC_A6, EVENTOUT	-
-	-	-	51	61	M8	V <sub>SS</sub>	S		-	-	-
-	-	-	52	62	N8	V <sub>DD</sub>	S		-	-	-
-	-	-	53	63	N6	PF13	I/O	FT	-	FSMC_A7, EVENTOUT	-
-	-	-	54	64	R7	PF14	I/O	FT	-	FSMC_A8, EVENTOUT	-
-	-	-	55	65	P7	PF15	I/O	FT	-	FSMC_A9, EVENTOUT	-
-	-	-	56	66	N7	PG0	I/O	FT	-	FSMC_A10, EVENTOUT	-
-	-	-	57	67	M7	PG1	I/O	FT	-	FSMC_A11, EVENTOUT	-

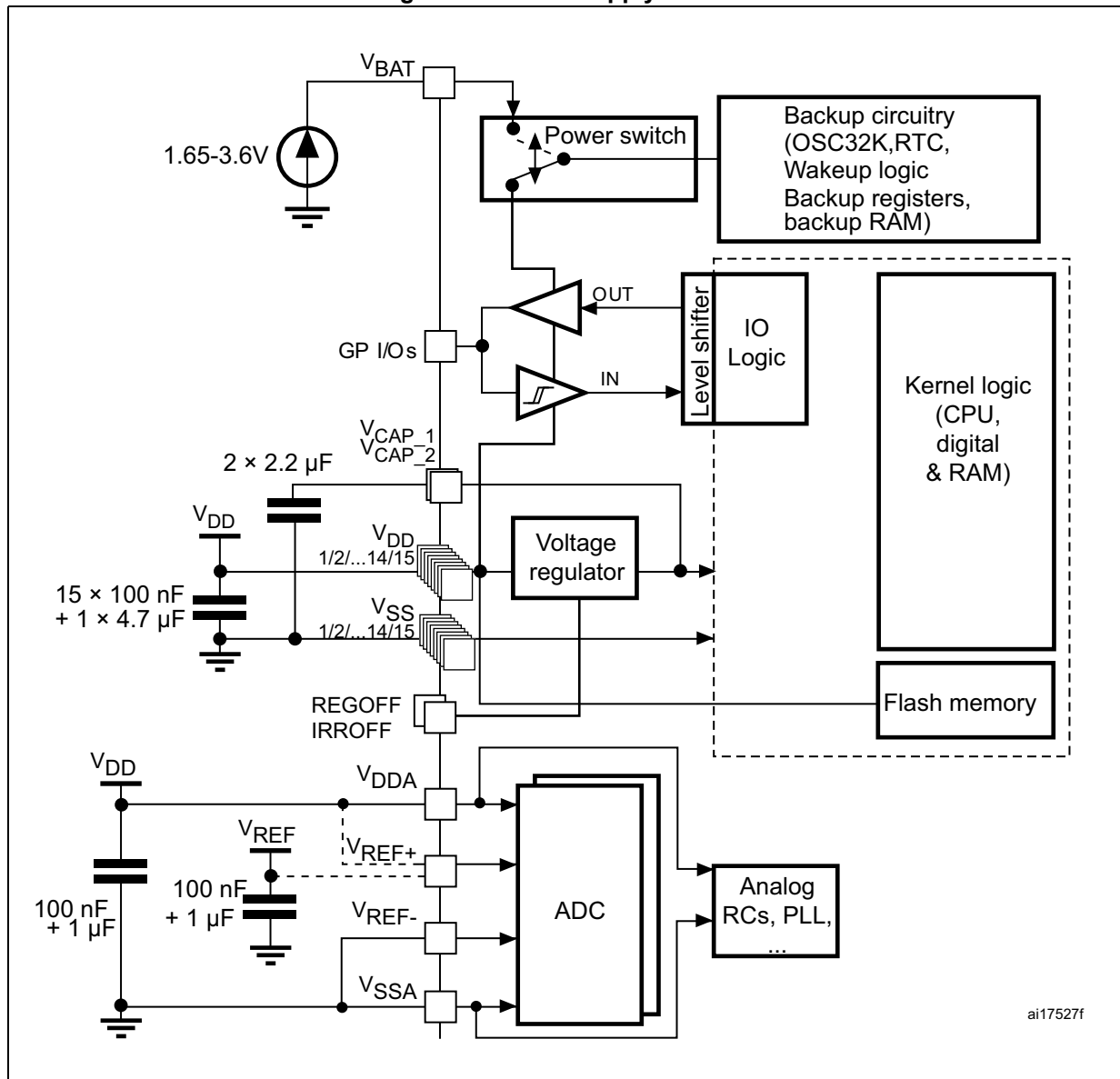
Table 8. STM32F20x pin and ball definitions (continued)

Pins						Pin name (function after reset) <sup>(1)</sup>	Pin type	I/O structure	Note	Alternate functions	Additional functions
LQFP64	WLCSP64+2	LQFP100	LQFP144	LQFP176	UFBGA176						
-	-	-	-	130	D13	PH15	I/O	FT	-	TIM8_CH3N, DCMI_D11, EVENTOUT	-
-	-	-	-	131	E14	PI0	I/O	FT	-	TIM5_CH4, SPI2_NSS, I2S2_WS, DCMI_D13, EVENTOUT	-
-	-	-	-	132	D14	PI1	I/O	FT	-	SPI2_SCK, I2S2_SCK, DCMI_D8, EVENTOUT	-
-	-	-	-	133	C14	PI2	I/O	FT	-	TIM8_CH4, SPI2_MISO, DCMI_D9, EVENTOUT	-
-	-	-	-	134	C13	PI3	I/O	FT	-	TIM8_ETR, SPI2_MOSI, I2S2_SD, DCMI_D10, EVENTOUT	-
-	-	-	-	135	D9	V <sub>SS</sub>	S	-	-	-	-
-	-	-	-	136	C9	V <sub>DD</sub>	S	-	-	-	-
49	A1	76	109	137	A14	PA14 (JTCK-SWCLK)	I/O	FT	-	JTCK-SWCLK, EVENTOUT	-
50	A2	77	110	138	A13	PA15 (JTDI)	I/O	FT	-	JTDI, SPI3_NSS, I2S3_WS, TIM2_CH1_ETR, SPI1_NSS, EVENTOUT	-
51	B3	78	111	139	B14	PC10	I/O	FT	-	SPI3_SCK, I2S3_SCK, UART4_TX, SDIO_D2, DCMI_D8, USART3_TX, EVENTOUT	-
52	C3	79	112	140	B13	PC11	I/O	FT	-	UART4_RX, SPI3_MISO, SDIO_D3, DCMI_D4, USART3_RX, EVENTOUT	-
53	A3	80	113	141	A12	PC12	I/O	FT	-	UART5_TX, SDIO_CK, DCMI_D9, SPI3_MOSI, I2S3_SD, USART3_CK, EVENTOUT	-
-	-	81	114	142	B12	PD0	I/O	FT	-	FSMC_D2, CAN1_RX, EVENTOUT	-
-	-	82	115	143	C12	PD1	I/O	FT	-	FSMC_D3, CAN1_TX, EVENTOUT	-



### 6.1.6 Power supply scheme

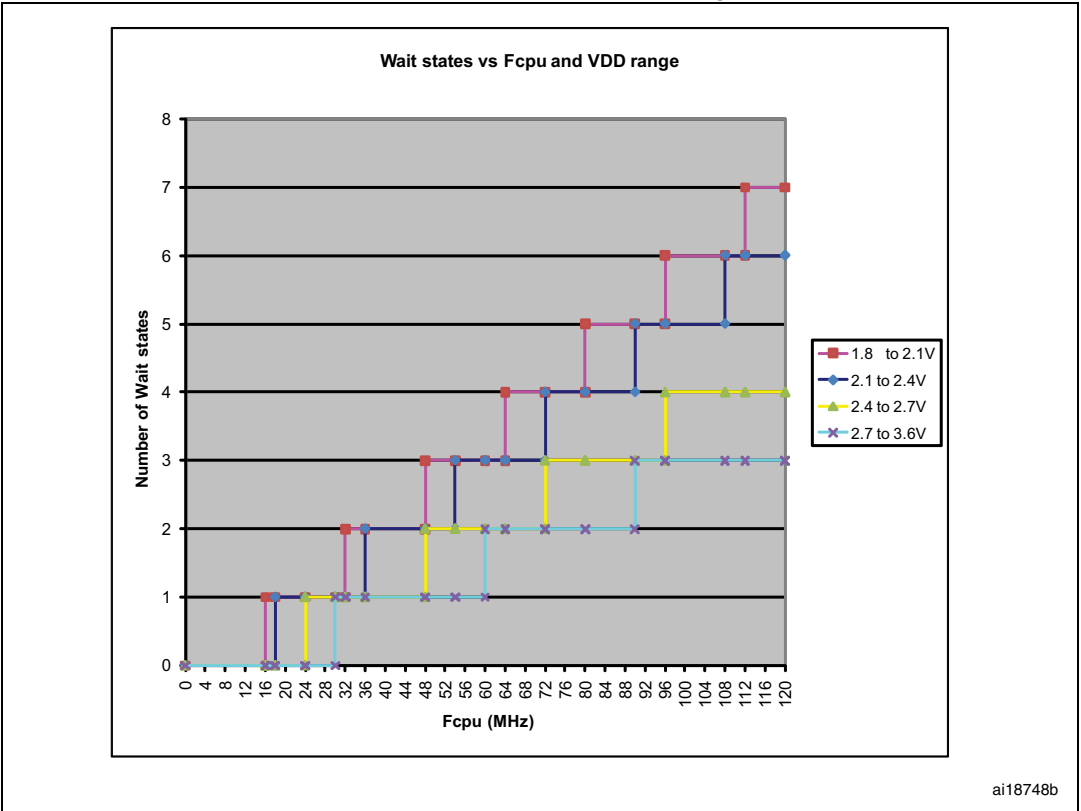
### Figure 19. Power supply scheme



1. Each power supply pair must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure the good functionality of the device.
2. To connect REGOFF and IRROFF pins, refer to [Section 3.16: Voltage regulator](#).
3. The two 2.2  $\mu\text{F}$  ceramic capacitors should be replaced by two 100 nF decoupling capacitors when the voltage regulator is OFF.
4. The 4.7  $\mu\text{F}$  ceramic capacitor must be connected to one of the  $V_{\text{DD}}$  pin.

**Caution:** Each power supply pair ( $V_{DD}/V_{SS}$ ,  $V_{DDA}/V_{SSA}$  ...) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB, to ensure good device operation. It is not recommended to remove filtering capacitors to reduce PCB size or cost. This might cause incorrect device operation.

Figure 21. Number of wait states versus  $f_{CPU}$  and  $V_{DD}$  range

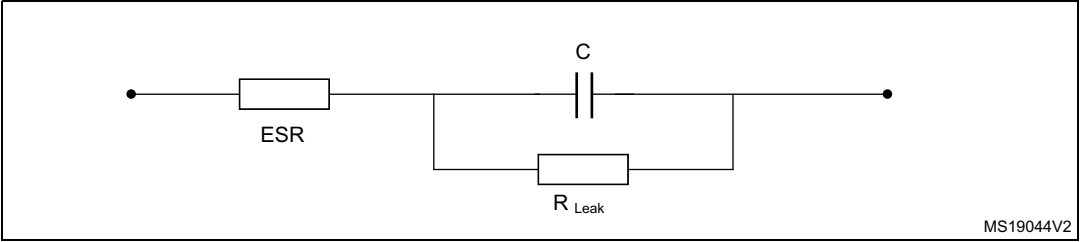


1. The supply voltage can drop to 1.7 V when the device operates in the 0 to 70 °C temperature range and IRROFF is set to  $V_{DD}$ .

### 6.3.2 VCAP1/VCAP2 external capacitor

Stabilization for the main regulator is achieved by connecting an external capacitor to the VCAP1/VCAP2 pins.  $C_{EXT}$  is specified in [Table 16](#).

Figure 22. External capacitor  $C_{EXT}$



1. Legend: ESR is the equivalent series resistance.

Table 16. VCAP1/VCAP2 operating conditions<sup>(1)</sup>

Symbol	Parameter	Conditions
CEXT	Capacitance of external capacitor	2.2 $\mu$ F
ESR	ESR of external capacitor	< 2 $\Omega$

1. When bypassing the voltage regulator, the two 2.2  $\mu$ F  $V_{CAP}$  capacitors are not required and should be replaced by two 100 nF decoupling capacitors.

### On-chip peripheral current consumption

The current consumption of the on-chip peripherals is given in [Table 26](#). The MCU is placed under the following conditions:

- At startup, all I/O pins are configured as analog inputs by firmware.
- All peripherals are disabled unless otherwise mentioned
- The given value is calculated by measuring the current consumption
  - with all peripherals clocked off
  - with one peripheral clocked on (with only the clock applied)
- The code is running from Flash memory and the Flash memory access time is equal to 3 wait states at 120 MHz
- Prefetch and Cache ON
- When the peripherals are enabled, HCLK = 120MHz,  $f_{PCLK1} = f_{HCLK}/4$ , and  $f_{PCLK2} = f_{HCLK}/2$
- The typical values are obtained for  $V_{DD} = 3.3\text{ V}$  and  $T_A = 25\text{ °C}$ , unless otherwise specified.

**Table 26. Peripheral current consumption**

Peripheral <sup>(1)</sup>		Typical consumption at 25 °C	Unit
AHB1	GPIO A	0.45	mA
	GPIO B	0.43	
	GPIO C	0.46	
	GPIO D	0.44	
	GPIO E	0.44	
	GPIO F	0.42	
	GPIO G	0.44	
	GPIO H	0.42	
	GPIO I	0.43	
	OTG_HS + ULPI	3.64	
	CRC	1.17	
	BKPSRAM	0.21	
	DMA1	2.76	
	DMA2	2.85	
	ETH_MAC + ETH_MAC_TX ETH_MAC_RX ETH_MAC_PTP	2.99	
AHB2	OTG_FS	3.16	
	DCMI	0.60	
AHB3	FSMC	1.74	

The test results are given in [Table 41](#). They are based on the EMS levels and classes defined in application note AN1709.

**Table 41. EMS characteristics**

Symbol	Parameter	Conditions	Level/Class
$V_{FESD}$	Voltage limits to be applied on any I/O pin to induce a functional disturbance	$V_{DD} = 3.3\text{ V}$ , LQFP176, $T_A = +25\text{ }^{\circ}\text{C}$ , $f_{HCLK} = 120\text{ MHz}$ , conforms to IEC 61000-4-2	2B
$V_{EFTB}$	Fast transient voltage burst limits to be applied through 100 pF on $V_{DD}$ and $V_{SS}$ pins to induce a functional disturbance	$V_{DD} = 3.3\text{ V}$ , LQFP176, $T_A = +25\text{ }^{\circ}\text{C}$ , $f_{HCLK} = 120\text{ MHz}$ , conforms to IEC 61000-4-2	4A

### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

#### Software recommendations

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)

#### Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

**USB OTG FS characteristics**

The USB OTG interface is USB-IF certified (Full-Speed). This interface is present in both the USB OTG HS and USB OTG FS controllers.

**Table 56. USB OTG FS startup time**

Symbol	Parameter	Max	Unit
$t_{\text{STARTUP}}^{(1)}$	USB OTG FS transceiver startup time	1	$\mu\text{s}$

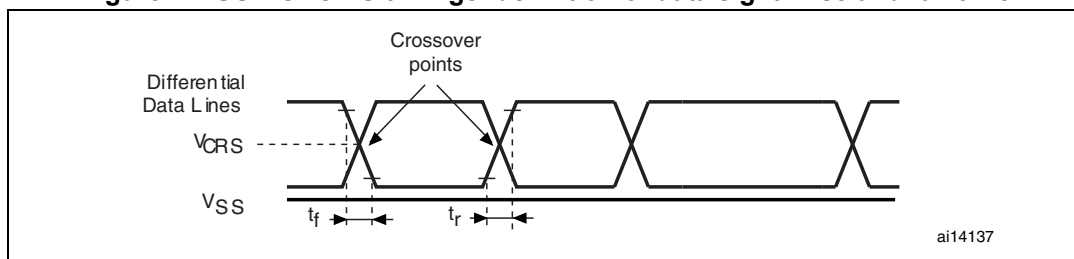
1. Guaranteed by design, not tested in production.

**Table 57. USB OTG FS DC electrical characteristics**

Symbol		Parameter	Conditions	Min. <sup>(1)</sup>	Typ.	Max. <sup>(1)</sup>	Unit
Input levels	V <sub>DD</sub>	USB OTG FS operating voltage		3.0 <sup>(2)</sup>	-	3.6	V
	V <sub>DI</sub> <sup>(3)</sup>	Differential input sensitivity	I(USB_FS_DP/DM, USB_HS_DP/DM)	0.2	-	-	V
	V <sub>CM</sub> <sup>(3)</sup>	Differential common mode range	Includes V <sub>DI</sub> range	0.8	-	2.5	
	V <sub>SE</sub> <sup>(3)</sup>	Single ended receiver threshold		1.3	-	2.0	
Output levels	V <sub>OL</sub>	Static output level low	R <sub>L</sub> of 1.5 kΩ to 3.6 V <sup>(4)</sup>	-	-	0.3	V
	V <sub>OH</sub>	Static output level high	R <sub>L</sub> of 15 kΩ to V <sub>SS</sub> <sup>(4)</sup>	2.8	-	3.6	
R <sub>PD</sub>		PA11, PA12, PB14, PB15 (USB_FS_DP/DM, USB_HS_DP/DM)	V <sub>IN</sub> = V <sub>DD</sub>	17	21	24	kΩ
		PA9, PB13 (OTG_FS_VBUS, OTG_HS_VBUS)		0.65	1.1	2.0	
R <sub>PU</sub>		PA12, PB15 (USB_FS_DP, USB_HS_DP)	V <sub>IN</sub> = V <sub>SS</sub>	1.5	1.8	2.1	
		PA9, PB13 (OTG_FS_VBUS, OTG_HS_VBUS)	V <sub>IN</sub> = V <sub>SS</sub>	0.25	0.37	0.55	

1. All the voltages are measured from the local ground potential.
2. The STM32F205xx and STM32F207xx USB OTG FS functionality is ensured down to 2.7 V but not the full USB OTG FS electrical characteristics which are degraded in the 2.7-to-3.0 V  $V_{\text{DD}}$  voltage range.
3. Guaranteed by design, not tested in production.
4.  $R_{\text{L}}$  is the load connected on the USB OTG FS drivers

Figure 47. USB OTG FS timings: definition of data signal rise and fall time

Table 58. USB OTG FS electrical characteristics<sup>(1)</sup>

Driver characteristics					
Symbol	Parameter	Conditions	Min	Max	Unit
$t_r$	Rise time <sup>(2)</sup>	$C_L = 50 \text{ pF}$	4	20	ns
$t_f$	Fall time <sup>(2)</sup>	$C_L = 50 \text{ pF}$	4	20	ns
$t_{rfm}$	Rise/fall time matching	$t_r/t_f$	90	110	%
$V_{CRS}$	Output signal crossover voltage	-	1.3	2.0	V

1. Guaranteed by design, not tested in production.
2. Measured from 10% to 90% of the data signal. For more detailed informations, please refer to USB Specification - Chapter 7 (version 2.0).

## USB HS characteristics

Table 59 shows the USB HS operating voltage.

Table 59. USB HS DC electrical characteristics

Symbol	Parameter	Min. <sup>(1)</sup>	Max. <sup>(1)</sup>	Unit
Input level $V_{DD}$	USB OTG HS operating voltage	2.7	3.6	V

1. All the voltages are measured from the local ground potential.

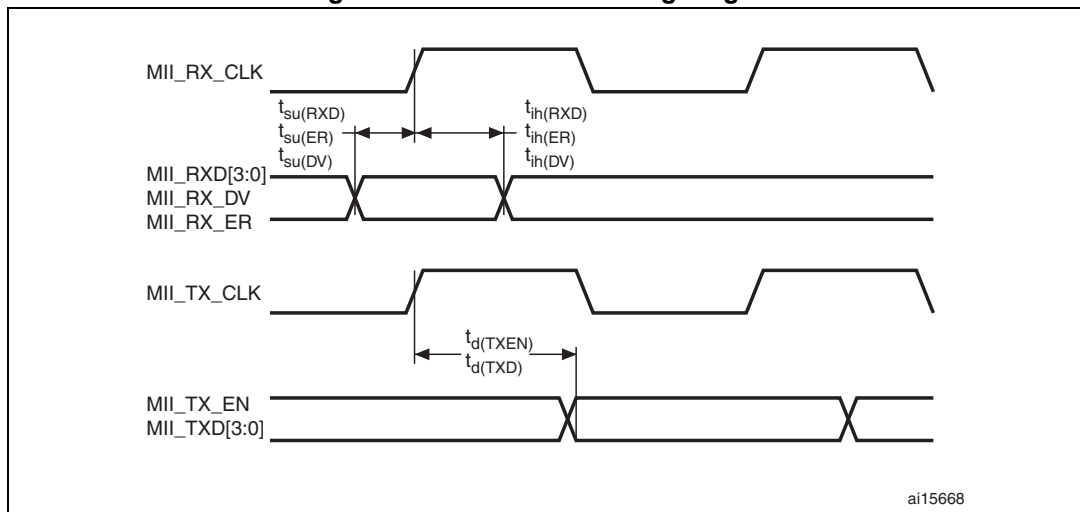
Table 60. Clock timing parameters

Parameter <sup>(1)</sup>		Symbol	Min	Nominal	Max	Unit
Frequency (first transition)	8-bit $\pm 10\%$	$F_{START\_8BIT}$	54	60	66	MHz
Frequency (steady state)	$\pm 500 \text{ ppm}$	$F_{STEADY}$	59.97	60	60.03	MHz
Duty cycle (first transition)	8-bit $\pm 10\%$	$D_{START\_8BIT}$	40	50	60	%
Duty cycle (steady state)	$\pm 500 \text{ ppm}$	$D_{STEADY}$	49.975	50	50.025	%
Time to reach the steady state frequency and duty cycle after the first transition		$T_{STEADY}$	-	-	1.4	ms
Clock startup time after the de-assertion of SuspendM	Peripheral	$T_{START\_DEV}$	-	-	5.6	ms
	Host	$T_{START\_HOST}$	-	-	-	
PHY preparation time after the first transition of the input clock		$T_{PREP}$	-	-	-	$\mu\text{s}$

1. Guaranteed by design, not tested in production.

[Table 65](#) gives the list of Ethernet MAC signals for MII and [Figure 50](#) shows the corresponding timing diagram.

**Figure 51. Ethernet MII timing diagram**



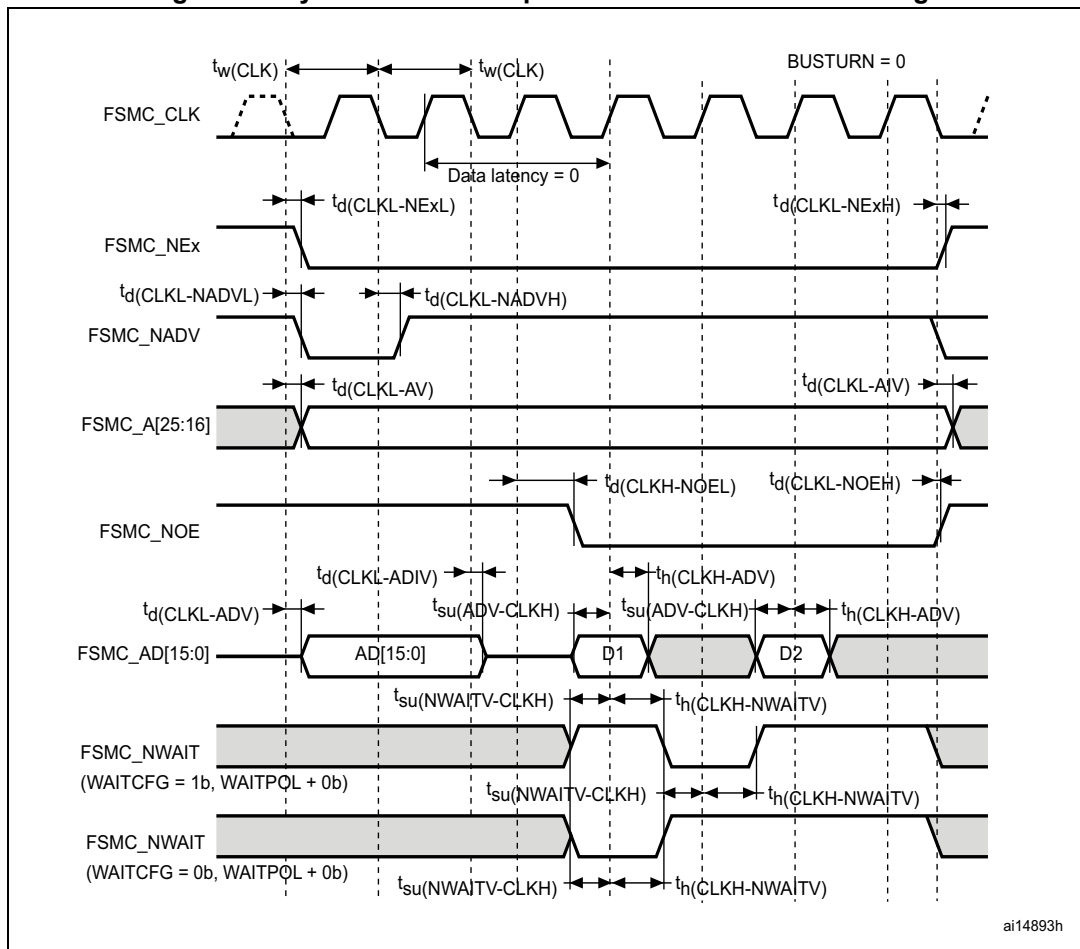
**Table 65. Dynamics characteristics: Ethernet MAC signals for MII**

Symbol	Rating	Min	Typ	Max	Unit
$t_{su}(RXD)$	Receive data setup time	7.5	-	-	ns
$t_{oh}(RXD)$	Receive data hold time	1	-	-	ns
$t_{su}(DV)$	Data valid setup time	4	-	-	ns
$t_{oh}(DV)$	Data valid hold time	0	-	-	ns
$t_{su}(ER)$	Error setup time	3.5	-	-	ns
$t_{oh}(ER)$	Error hold time	0	-	-	ns
$t_d(TXEN)$	Transmit enable valid delay time	-	11	14	ns
$t_d(TXD)$	Transmit data valid delay time	-	11	14	ns

### CAN (controller area network) interface

Refer to [Section 6.3.16: I/O port characteristics](#) for more details on the input/output alternate function characteristics (CANTX and CANRX).

### Figure 61. Synchronous multiplexed NOR/PSRAM read timings



**Table 76. Synchronous multiplexed NOR/PSRAM read timings<sup>(1)(2)</sup>**

Symbol	Parameter	Min	Max	Unit
$t_{w(CLK)}$	FSMC_CLK period	$2T_{HCLK}$	-	ns
$t_{d(CLKL-NExL)}$	FSMC_CLK low to FSMC_NEx low (x=0..2)	-	0	ns
$t_{d(CLKL-NExH)}$	FSMC_CLK low to FSMC_NEx high (x= 0...2)	1	-	ns
$t_{d(CLKL-NADV_L)}$	FSMC_CLK low to FSMC_NADV low	-	1.5	ns
$t_{d(CLKL-NADV_H)}$	FSMC_CLK low to FSMC_NADV high	2.5	-	ns
$t_{d(CLKL-AV)}$	FSMC_CLK low to FSMC_Ax valid (x=16...25)	-	0	ns
$t_{d(CLKL-AIV)}$	FSMC_CLK low to FSMC_Ax invalid (x=16...25)	0	-	ns
$t_{d(CLKH-NOEL)}$	FSMC_CLK high to FSMC_NOE low	-	1	ns
$t_{d(CLKL-NOEH)}$	FSMC_CLK low to FSMC_NOE high	1	-	ns
$t_{d(CLKL-ADV)}$	FSMC_CLK low to FSMC_AD[15:0] valid	-	3	ns
$t_{d(CLKL-ADIV)}$	FSMC_CLK low to FSMC_AD[15:0] invalid	0	-	ns



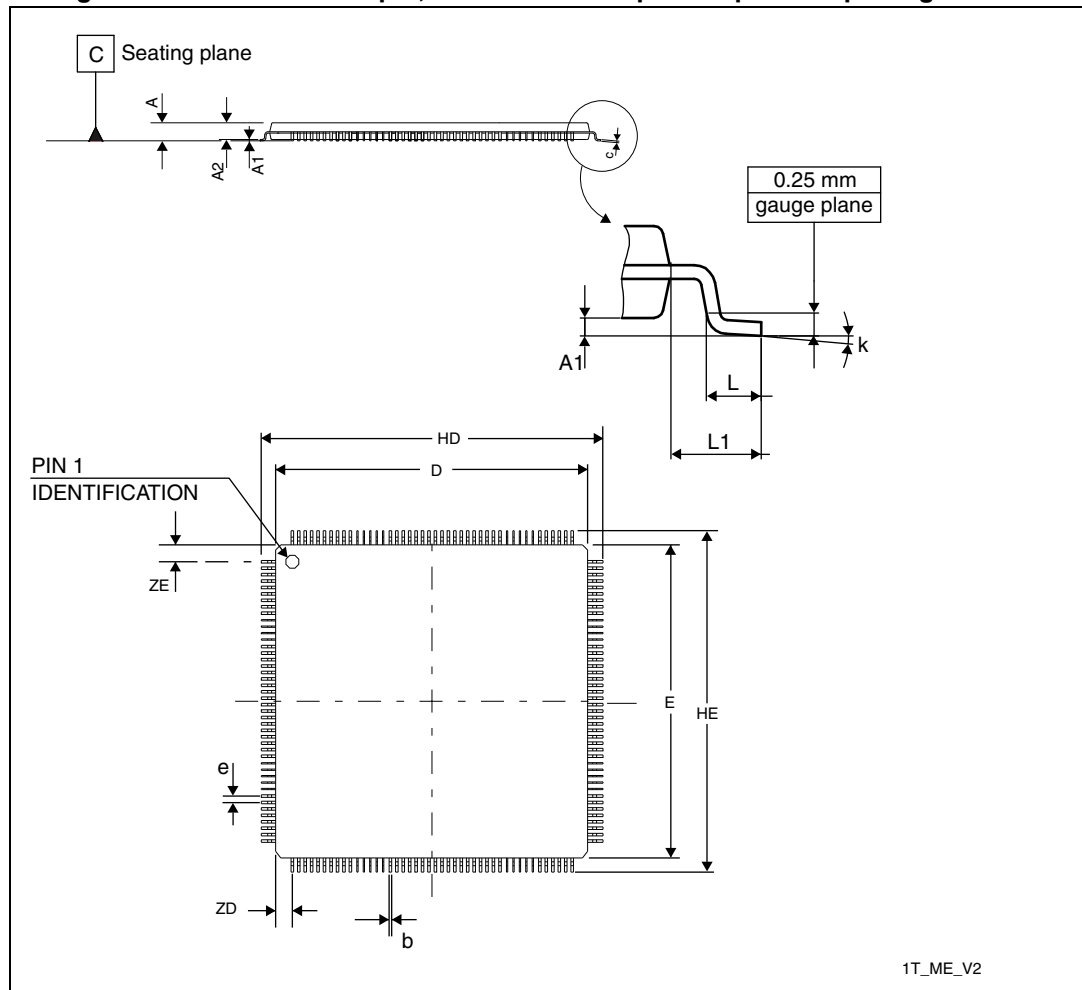
**Table 91. LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package mechanical data**

Symbol	millimeters			inches <sup>(1)</sup>		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	21.800	22.000	22.200	0.8583	0.8661	0.8740
D1	19.800	20.000	20.200	0.7795	0.7874	0.7953
D3	-	17.500	-	-	0.6890	-
E	21.800	22.000	22.200	0.8583	0.8661	0.8740
E1	19.800	20.000	20.200	0.7795	0.7874	0.7953
E3	-	17.500	-	-	0.6890	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0°	3.5°	7°	0°	3.5°	7°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

## 7.5 LQFP176 package information

Figure 87. LQFP176 - 176-pin, 24 x 24 mm low profile quad flat package outline

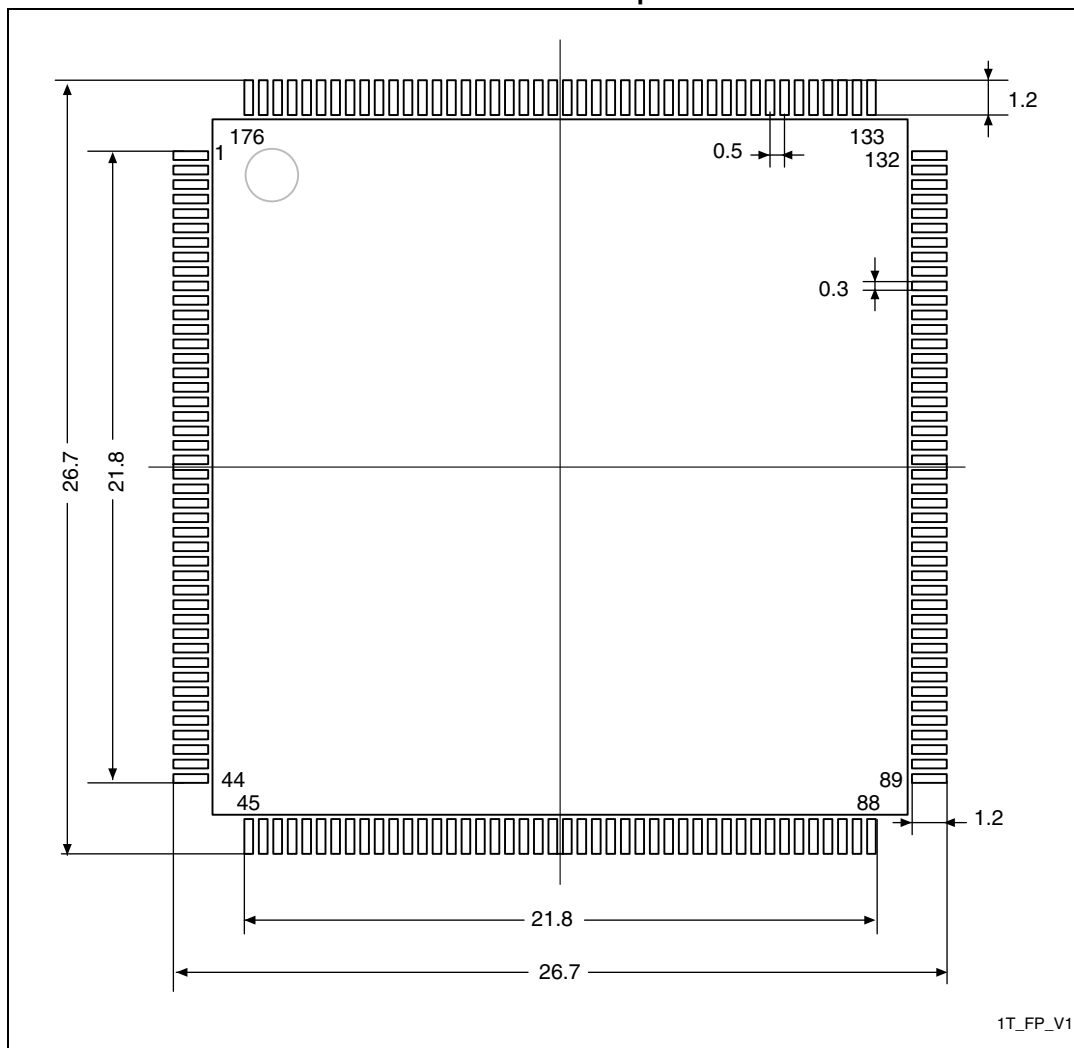


1. Drawing is not to scale.

Table 92. LQFP176 - 176-pin, 24 x 24 mm low profile quad flat package mechanical data

Symbol	Dimensions					
	millimeters			inches <sup>(1)</sup>		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	-	1.450	0.0531	-	0.0571
b	0.170	-	0.270	0.0067	-	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	23.900	-	24.100	0.9409	-	0.9488

Figure 88. LQFP176 - 176-pin, 24 x 24 mm low profile quad flat package recommended footprint



1. Dimensions are expressed in millimeters.

Table 97. Document revision history (continued)

Date	Revision	Changes
22-Apr-2011	6	<p>Changed datasheet status to "Full Datasheet".</p> <p>Introduced concept of SRAM1 and SRAM2.</p> <p>LQFP176 package now in production and offered only for 256 Kbyte and 1 Mbyte devices. Availability of WLCSP64+2 package limited to 512 Kbyte and 1 Mbyte devices.</p> <p>Updated <a href="#">Figure 3: Compatible board design between STM32F10xx and STM32F2xx for LQFP144 package</a> and <a href="#">Figure 2: Compatible board design between STM32F10xx and STM32F2xx for LQFP100 package</a>.</p> <p>Added camera interface for STM32F207Vx devices in <a href="#">Table 2: STM32F205xx features and peripheral counts</a>.</p> <p>Removed 16 MHz internal RC oscillator accuracy in <a href="#">Section 3.12: Clocks and startup</a>.</p> <p>Updated <a href="#">Section 3.16: Voltage regulator</a>.</p> <p>Modified I<sup>2</sup>S sampling frequency range in <a href="#">Section 3.12: Clocks and startup</a>, <a href="#">Section 3.24: Inter-integrated sound (I2S)</a>, and <a href="#">Section 3.30: Audio PLL (PLL12S)</a>.</p> <p>Updated <a href="#">Section 3.17: Real-time clock (RTC), backup SRAM and backup registers</a> and description of TIM2 and TIM5 in <a href="#">Section 3.20.2: General-purpose timers (TIMx)</a>.</p> <p>Modified maximum baud rate (oversampling by 16) for USART1 in <a href="#">Table 6: USART feature comparison</a>.</p> <p>Updated note related to RFU pin below <a href="#">Figure 12: STM32F20x LQFP100 pinout</a>, <a href="#">Figure 13: STM32F20x LQFP144 pinout</a>, <a href="#">Figure 14: STM32F20x LQFP176 pinout</a>, <a href="#">Figure 15: STM32F20x UFBGA176 ballout</a>, and <a href="#">Table 8: STM32F20x pin and ball definitions</a>.</p> <p>In <a href="#">Table 8: STM32F20x pin and ball definitions</a>, changed I2S2_CK and I2S3_CK to I2S2_SCK and I2S3_SCK, respectively; added PA15 and TT (3.6 V tolerant I/O).</p> <p>Added RTC_50Hz as PB15 alternate function in <a href="#">Table 8: STM32F20x pin and ball definitions</a> and <a href="#">Table 10: Alternate function mapping</a>.</p> <p>Removed ETH_RMII_TX_CLK for PC3/AF11 in <a href="#">Table 10: Alternate function mapping</a>.</p> <p>Updated <a href="#">Table 11: Voltage characteristics</a> and <a href="#">Table 12: Current characteristics</a>.</p> <p>T<sub>STG</sub> updated to -65 to +150 in <a href="#">Table 13: Thermal characteristics</a>.</p> <p>Added CEXT, ESL, and ESR in <a href="#">Table 14: General operating conditions</a> as well as <a href="#">Section 6.3.2: VCAP1/VCAP2 external capacitor</a>.</p> <p>Modified <a href="#">Note 4</a> in <a href="#">Table 15: Limitations depending on the operating power supply range</a>.</p> <p>Updated <a href="#">Table 17: Operating conditions at power-up / power-down (regulator ON)</a>, and <a href="#">Table 18: Operating conditions at power-up / power-down (regulator OFF)</a>.</p> <p>Added OSC_OUT pin in <a href="#">Figure 17: Pin loading conditions</a>, and <a href="#">Figure 18: Pin input voltage</a>.</p> <p>Updated <a href="#">Figure 19: Power supply scheme</a> to add IRROFF and REGOFF pins and modified notes.</p> <p>Updated V<sub>PVD</sub>, V<sub>BOR1</sub>, V<sub>BOR2</sub>, V<sub>BOR3</sub>, T<sub>RSTTEMPO</sub> typical value, and I<sub>RUSH</sub>, added E<sub>RUSH</sub> and <a href="#">Note 2</a> in <a href="#">Table 19: Embedded reset and power control block characteristics</a>.</p>

Table 97. Document revision history (continued)

Date	Revision	Changes
20-Dec-2011	8 (continued)	<p>Added maximum power consumption at <math>T_A=25\text{ }^{\circ}\text{C}</math> in <a href="#">Table 23: Typical and maximum current consumptions in Stop mode</a>.</p> <p>Updated md minimum value in <a href="#">Table 36: SSCG parameters constraint</a>.</p> <p>Added examples in <a href="#">Section 6.3.11: PLL spread spectrum clock generation (SSCG) characteristics</a>.</p> <p>Updated <a href="#">Table 54: SPI characteristics</a> and <a href="#">Table 55: I2S characteristics</a>.</p> <p>Updated <a href="#">Figure 48: ULPI timing diagram</a> and <a href="#">Table 61: ULPI timing</a>.</p> <p>Updated <a href="#">Table 63: Dynamics characteristics: Ethernet MAC signals for SMI</a>, <a href="#">Table 64: Dynamics characteristics: Ethernet MAC signals for RMII</a>, and <a href="#">Table 65: Dynamics characteristics: Ethernet MAC signals for MII</a>.</p> <p><a href="#">Section 6.3.25: FSMC characteristics</a>: updated <a href="#">Table 72</a> to <a href="#">Table 83</a>, changed <math>C_L</math> value to 30 pF, and modified FSMC configuration for asynchronous timings and waveforms. Updated <a href="#">Figure 62: Synchronous multiplexed PSRAM write timings</a>.</p> <p>Updated <a href="#">Table 84: DCMI characteristics</a>.</p> <p>Updated <a href="#">Table 92: UFBGA176+25 - ultra thin fine pitch ball grid array 10 × 10 × 0.6 mm mechanical data</a>.</p> <p>Updated <a href="#">Table 96: Ordering information scheme</a>.</p> <p>Appendix <a href="#">A.2: USB OTG full speed (FS) interface solutions</a>: updated <a href="#">Figure 87: USB OTG FS (full speed) host-only connection</a> and added <a href="#">Note 2</a>, updated <a href="#">Figure 88: OTG FS (full speed) connection dual-role with internal PHY</a> and added <a href="#">Note 3</a> and <a href="#">Note 4</a>, modified <a href="#">Figure 89: OTG HS (high speed) device connection, host and dual-role in high-speed mode with external PHY</a> and added <a href="#">Note 2</a>.</p> <p>Appendix <a href="#">A.3: USB OTG high speed (HS) interface solutions</a>: removed figures <a href="#">USB OTG HS device-only connection in FS mode</a> and <a href="#">USB OTG HS host-only connection in FS mode</a>, updated <a href="#">Figure 89: OTG HS (high speed) device connection, host and dual-role in high-speed mode with external PHY</a>.</p> <p>Added Appendix <a href="#">A.4: Ethernet interface solutions</a>.</p> <p>Updated disclaimer on last page.</p>
24-Apr-2012	9	<p>Updated <math>V_{DD}</math> minimum value in <a href="#">Section 2: Description</a>.</p> <p>Updated number of USB OTG HS and FS, modified packages for STM32F2071x part numbers, added <a href="#">Note 1</a> related to FSMC and <a href="#">Note 2</a> related to SPI/I2S, and updated <a href="#">Note 3</a> in <a href="#">Table 2: STM32F205xx features and peripheral counts</a> and <a href="#">Table 3: STM32F207xx features and peripheral counts</a>.</p> <p>Added <a href="#">Note 2</a> and update TIM5 in <a href="#">Figure 4: STM32F20x block diagram</a>.</p> <p>Updated maximum number of maskable interrupts in <a href="#">Section 3.10: Nested vectored interrupt controller (NVIC)</a>.</p> <p>Updated <math>V_{DD}</math> minimum value in <a href="#">Section 3.14: Power supply schemes</a>.</p> <p>Updated <a href="#">Note a</a> in <a href="#">Section 3.16.1: Regulator ON</a>.</p> <p>Removed STM32F205xx in <a href="#">Section 3.28: Universal serial bus on-the-go full-speed (OTG_FS)</a>.</p>